

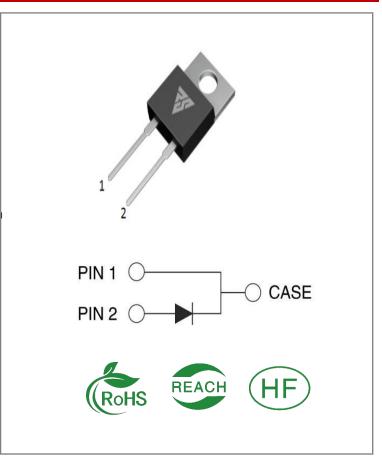
VRRM	IF (TC≤135℃)	QC	
650V	18A	36nC	

Applications:

- Switch Mode Power Supplies
- Power Factor Correction
- Motor drive, PV Inverter, Wind Power Station

Features:

- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- Positive Temperature Coefficient on VF
- Temperature-independent Switching
- 175°C Operating Junction Temperature



Benefits:

- Replace Bipolar with Unipolar Device
- Reduction of Heat Sink Size
- Parallel Devices Without Thermal Runaway
- Essentially No Switching Losses

Ordering Information

Part Number	Package	Marking	Packing	Qty.
RSS15065A	TO-220-2	RSS15065A	Tube	50 PCS



Maximum Ratings (TJ= 25°C unless otherwise specified)

Symbol	Parameter	Valu e	Unit	Test Conditions	Not e
VRRM	Repetitive Peak Reverse Voltage	650	V	TC = 25℃	
VRSM	Surge Peak Reverse Voltage	650	V	TC = 25°C	
VR	DC Blocking Voltage	650	V	TC = 25℃	
IF	Forward Current	18 15	Α	TC ≤ 135°C TC ≤ 149°C	
IFRM	Repetitive Peak Forward Surge Current	40	Α	TC = 25° C, tp = 8.3ms, Half Sine Wave	
Ptot	Power Dissipation	135	W	TC = 25°C	Fig.
TC	Maximum Case Temperature	149	${\mathbb C}$		
TJ,TST G	Operating Junction and Storage Temperature	-55 to17 5	$^{\circ}\! \mathbb{C}$		

Electrical Characteristics (TJ= 25 °C unless otherwise specified)

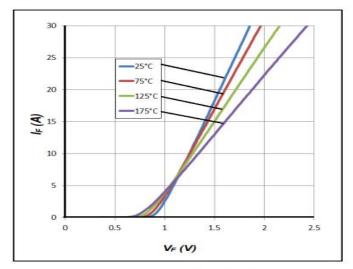
Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note	
VF	Forward Voltage	1.4	1.65	V	IF = 15A, TJ = 25℃	Fig. 1	
		1.7	2.3	\ v	IF = 15A, TJ = 175℃	Fig.1	
IR R	Reverse Current	2	20		VR = 650V, TJ = 25℃	Fig 2	
		10	200	μΑ	VR = 650V, TJ = 175℃	Fig.2	
		865			VR = 1V, TJ = 25°C, f = 1MHz		
С	Total Capacitance	88	/	рF	VR = 200V, TJ = 25°C, f = 1MHz	Fig.5	
		72			VR = 400V, TJ = 25°C, f = 1MHz		
QC	Total Capacitive Charge	36	/	nC	VR =650V,	Fig.4	

Thermal Characteristics (TJ= 25°C unless otherwise specified)

Symbol	Parameter	Тур.	Unit	Note
RθJC	Thermal Resistance from Junction to Case	0.95	°C/W	Fig.6



Typical Feature Curve





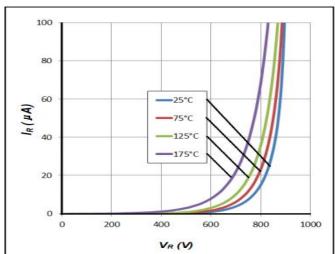


Figure 2. Reverse Characteristics

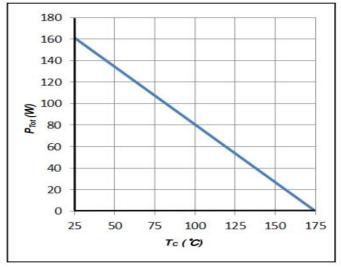


Figure 3. Power Derating

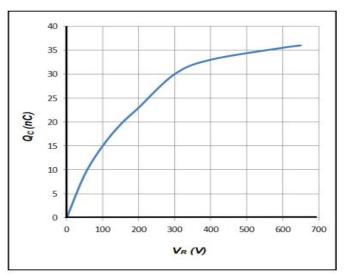


Figure 4. Total Capacitive Charge vs. Reverse Voltage

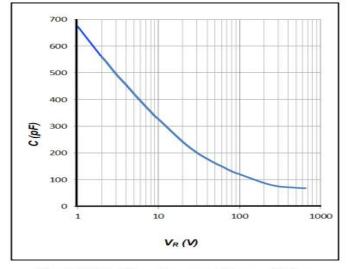


Figure 5. Total Capacitance vs. Reverse Voltage

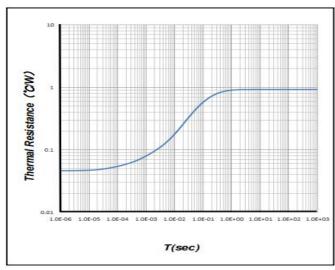
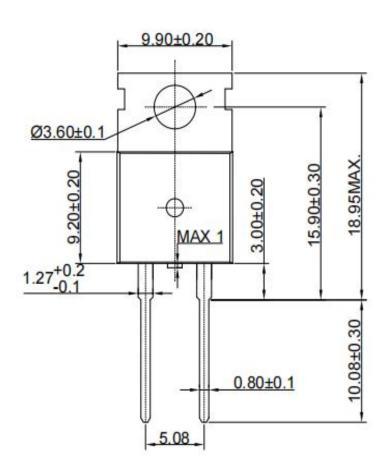


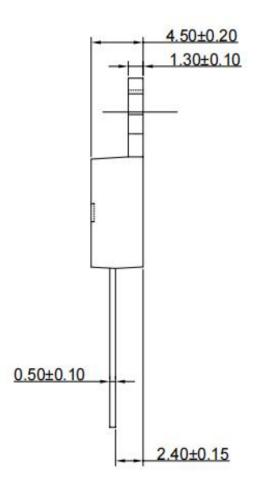
Figure 6. Transient Thermal Impedance

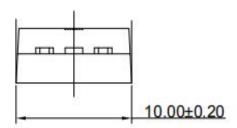
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Package outline drawing(TO-220 Unit: mm)









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- c.whose failuer to when properly used in accordance with instructions for used provided in the laeling, can be reasonably expected to result in significant injury to the user.

2.A critical component is any component of a life support device or system whose failure to system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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